







**TPS22950** 

#### ZHCSMW7B - DECEMBER 2020 - REVISED FEBRUARY 2023

# TPS22950x 5.5V、3.2A、34mQ 可调限流负载开关

### 1 特性

输入电压范围 (V<sub>IN</sub>): 1.8 V 至 5.5 V

输出电流限制 (I<sub>LIMIT</sub>): 0.05A - 3.5A (典型值)

• TPS22950:自动重试电流限制响应

• TPS22950L:闭锁电流限制响应

• 热关断 (TSD)

导通电阻(R<sub>ON</sub>):

- V<sub>IN</sub> = 5V 时,R<sub>ON</sub>: 34mΩ(典型值)

- V<sub>IN</sub> = 3.3V 时,R<sub>ON</sub>:41mΩ(典型值)

• 慢速开通时序可限制浪涌电流(典型值):

- V<sub>IN</sub> = 5V 时,t<sub>ON</sub>:800µs

- V<sub>IN</sub> = 3.3V 时,t<sub>ON</sub>:550µs

• 常开的反向电流阻断 (TPS22950)

• 故障指示 (FLT)

快速输出放电 (QOD): 150 Ω

ON 引脚智能下拉电阻 (R<sub>PD.ON</sub>):

- ON ≥ V<sub>IH</sub> (I<sub>ON</sub>): 50nA (最大值)

- ON ≤ V<sub>II</sub> (R<sub>PD ON</sub>): 500kΩ ( 典型值 )

低功耗:

- 导通状态 (I<sub>Q</sub>): 40μA ( 典型值 )

- 关闭状态 (I<sub>SD</sub>): 0.2µA (典型值)

• UL 2367 认证 - 文件号 E169910

- 已通过 I<sub>LIM</sub> = 66mA 至 2.46A 认证

#### 2 应用

- 个人电子产品
- 平板电脑
- 笔记本电脑
- 游戏机
- 附件

### 3 说明

TPS22950x 器件是一款小型单通道负载开关,能够通 过可调输出电流限制、反向电流阻断和热关断提供强大 的故障保护功能。

开关导通状态由数字输入控制,此输入可与低压控制信 号直接连接。首次加电时,此器件使用智能下拉电阻来 保持 ON 引脚不悬空,直到系统时序控制完成。故意 将引脚驱动为高电平 (>V<sub>IH</sub>) 后,智能下拉电阻会断 开,以防止不必要的功率损耗。

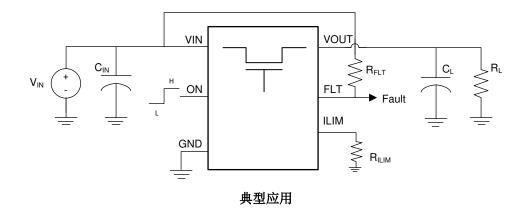
TPS22950/C 通过自动重试行为响应过流事件,而 TPS22950L 使用去抖时间和闭锁行为。

TPS22950x 采用标准 WCSP 封装和引线式 SOT 封 装,工作环境温度范围为-40°C至125°C。

#### 封装信息

器件型号	封装 <sup>(1)</sup>	封装尺寸(标称值)		
TPS22950、 TPS22950L	WCSP (6)	1.106mm × 0.706mm		
TPS22950C	DDC (SOT, 6)	2.90mm x 2.80mm		

(1) 要了解所有可用封装,请见数据表末尾的可订购产品附录。





### **Table of Contents**

1 特性	1	9.2 Functional Block Diagram	12
2 应用		9.3 Feature Description	12
- <del>,                                 </del>		9.4 Device Functional Modes	15
4 Revision History		10 Application and Implementation	17
5 Device Comparison Table		10.1 Application Information	17
6 Pin Configuration and Functions		10.2 Typical Application	17
7 Specifications		10.3 Power Supply Recommendations	18
7.1 Absolute Maximum Ratings		10.4 Layout	18
7.2 ESD Ratings		11 Device and Documentation Support	<mark>2</mark> 0
7.3 Recommended Operating Conditions		11.1 接收文档更新通知	20
7.4 Thermal Information		11.2 支持资源	<mark>2</mark> 0
7.5 Electrical Characteristics	<mark>6</mark>	11.3 Trademarks	<mark>2</mark> 0
7.6 Switching Characteristics	7	11.4 静电放电警告	<mark>2</mark> 0
7.7 Typical Characteristics		11.5 术语表	20
8 Parameter Measurement Information		12 Mechanical, Packaging, and Orderable	
9 Detailed Description	12	Information	21
9.1 Overview			

4 Revision History 注:以前版本的页码可能与当前版本的页码不同

C	Changes from Revision A (June 2022) to Revision B (February 2023)	Page
•	向数据表添加了 TPS22950C 可订购信息	1
C	Changes from Revision * (December 2020) to Revision A (June 2022)	Page
•	向数据表添加了 TPS22950L 可订购信息	1
•	Updated ESD ratings table to the latest sandard	5
	Added line items in Electrical Characteristics to reflect TPS22950L parameters	
•	Updated the Overview section in Detailed Description to include device functionality	12
•	Added a Current Limiting section to describe the latch off functionality of TPS22950L	14

Product Folder Links: TPS22950



# **5 Device Comparison Table**

DEVICE NAME	ILIM Range	IMAX	ILIM Response	Debounce Time	RCB
TPS22950	0.05 A to 3.5 A	2.7A	Auto-Retry	No	Yes
TPS22950L	0.5 A to 3.5 A	2.7A	Latch Off	Yes	No
TPS22950C	0.5 A to 3.5 A	3.2A	Auto-Retry	No	Yes



# **6 Pin Configuration and Functions**

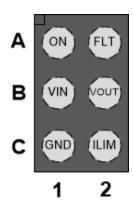


图 6-1. TPS22950x WCSP - 6 Top View

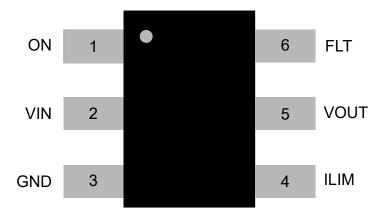


图 6-2. TPS22950x SOT- 6 Top View

表 6-1. Pin Functions

PIN		1/0	DECODINE	
NAME	WCSP	SOT6	I/O	DESCRIPTION
ON	A1	1	I	Active high switch control input. Do not leave floating.
FLT	A2	6	0	Open-drain output, pulled low during thermal shutdown or reverse current-conditions.
VIN	B1	2	I	Switch input
VOUT	B2	5	0	Switch output
GND	C1	3	_	Device ground
ILIM	C2	4	0	Adjusts device current limit through a resistor to ground.



### 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V <sub>IN</sub>	Maximum Input Voltage Range	- 0.3	6	V
V <sub>OUT</sub>	Maximum Output Voltage Range	- 0.3	6	V
V <sub>ON</sub>	Maximum ON Pin Voltage Range	- 0.3	6	V
V <sub>FLT</sub>	Maximum FLT Pin Voltage	- 0.3	6	V
I <sub>MAX</sub>	Maximum Continuous Output Current(TPS22950C)		3.2	Α
I <sub>MAX</sub>	Maximum Continuous Output Current(TPS22950,TPS22950L)		2.7	Α
I <sub>MAX,PLS</sub>	Maximum Pulsed Output Current (T <sub>J</sub> = 85°C, duty cycle = 2%)		4.1	Α
T <sub>STG</sub>	Storage temperature	- 65	150	°C
T <sub>LEAD</sub>	Maximum Lead Temperature (10 s soldering time)		300	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 7.2 ESD Ratings

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatio discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001 <sup>((1))</sup>		V
		Charged device model (CDM), per ANSI/ESDA/ JEDEC JS-002 <sup>((2))</sup>	±500	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	TYP MA	X UNIT
V <sub>IN</sub>	Input Voltage Range	1.8	5	5 V
V <sub>OUT</sub>	Output Voltage Range	0	5	5 V
V <sub>IH</sub>	ON Pin High Voltage Range	1	5	5 V
V <sub>IL</sub>	ON Pin Low Voltage Range	0	0.3	5 V
I <sub>LIM</sub>	Output Current Limit (TPS22950)	0.05	3	5 A
I <sub>LIM</sub>	Output Current Limit (TPS22950L)	0.5	3	5 A
T <sub>A</sub>	Ambient temperature	- 40	12	5 °C
TJ	Junction temperature	- 40	15	0 °C

### 7.4 Thermal Information

		TPS	TPS22950			
THERMAL METRIC <sup>(1)</sup>		DDC(SOT)	YBH (WCSP)	UNIT		
		6 PINS	6 PINS			
R <sub>0</sub> JA	Junction-to-ambient thermal resistance	104.8	135.8	°C/W		
R <sub>θ JC(top)</sub>	Junction-to-case (top) thermal resistance	57.6	1.4	°C/W		
R <sub>0</sub> JB	Junction-to-board thermal resistance	36.3	39.5	°C/W		
Ψлт	Junction-to-top characterization parameter	12.8	0.9	°C/W		

Product Folder Links: TPS22950

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

5

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



### 7.4 Thermal Information (continued)

		TPS2	22950	
	THERMAL METRIC <sup>(1)</sup>	DDC(SOT)	YBH (WCSP)	UNIT
		6 PINS	6 PINS	
ΨЈВ	Junction-to-board characterization parameter	36.0	39.5	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

#### 7.5 Electrical Characteristics

Unless otherwise noted, the characteristics in the following table apply across the recommended operating input voltage range with a load of  $C_1$  = 0.1  $\mu$ F,  $R_1$  = 100  $\Omega$ . Typical Values are at 5 V and  $T_A$  = 25°C.

	PARAMETER	TEST CONDI	TIONS	MIN	TYP	MAX	UNIT
Input Sup	oly (VIN)						
	V/IN Outlean and Outlean	V > V VOUT O	- 40°C to 85°C		44	60	μA
I <sub>Q, VIN</sub>	VIN Quiescent Current	V <sub>ON</sub> ≥ V <sub>IH</sub> , VOUT = Open	- 40°C to 125°C			60	μA
			25°C	1	0.2	0.4	μA
I <sub>SD, VIN</sub>	VIN Shutdown Current	$V_{ON} \leqslant V_{IL}$ , VOUT = GND	- 40°C to 85°C			4 60 60 2 0.4 9 46 4 41 49 54 1 51 62 68 7 90 105 116 2 2.46 1 1.25 5 0.62 5 0.066 1	μΑ
			- 40°C to 125°C				μΑ
ON-Resist	ance (RON)	1	-				-
			25°C		34	41	mΩ
		V <sub>IN</sub> = 5 V, I <sub>OUT</sub> = -200 mA	- 40°C to 85°C			49	mΩ
			- 40°C to 125°C			54	mΩ
		V <sub>IN</sub> = 3.3 V, I <sub>OUT</sub> = -200 mA	25°C		41	51	mΩ
ON-Resistan  Ron  Output Curre	ON-State Resistance		- 40°C to 85°C			62	mΩ
			- 40°C to 125°C			68	mΩ
		V <sub>IN</sub> = 1.8 V, I <sub>OUT</sub> = -200 mA	25°C		67	90	mΩ
			- 40°C to 85°C			105	mΩ
			- 40°C to 125°C			116	mΩ
Output Cu	rrent Limit (ILIM)						
		$R_{ILIM}$ = 610 $\Omega$ $V_{IN}$ $V_{OUT}$ = 0.5 $V$	- 40°C to 125°C	1.54	2	2.46	А
1	Output Current Limit	$R_{ILIM}$ = 1.15 k $\Omega$ $V_{IN}$ $V_{OUT}$ = 0.5 $V$	- 40°C to 125°C	0.75	1	1.25	Α
<b>I</b> LIM	Output Gurrent Limit	$R_{ILIM}$ = 2.21 k $\Omega$ $V_{IN}$ $V_{OUT}$ = 0.5 $V$	- 40°C to 125°C	0.38	0.5	0.62	Α
		$R_{ILIM}$ = 19.2 k $\Omega$ $V_{IN}$ $V_{OUT}$ = 0.5 $V$	- 40°C to 125°C	0.034	0.05	60 2 0.4 9 46 4 41 49 54 1 51 62 68 7 90 105 116 2 2.46 1 1.25 5 0.62 5 0.066	Α
		R <sub>ILIM</sub> = 624 Ω V <sub>IN</sub> - V <sub>OUT</sub> = 1 V	- 40°C to 125°C		2.1		Α
I <sub>LIM,PEAK</sub>	Output Current Limit Peak (TPS22950L)	R <sub>ILIM</sub> = 1.24 k Ω V <sub>IN</sub> - V <sub>OUT</sub> = 1 V	- 40°C to 125°C		1		Α
		$R_{ILIM}$ = 2.49 k $\Omega$ $V_{IN}$ $V_{OUT}$ = 1 $V$	- 40°C to 125°C		0.52		Α
t <sub>LIM</sub>	Current Limit Response Time	Output hard short (I <sub>OUT</sub> > I <sub>LIM</sub> )	- 40°C to 125°C		5		μs
t <sub>DEBOUNCE</sub>	Latch Off Debounce Time (TPS22950L)	V <sub>IN</sub> - V <sub>OUT</sub> = 0.5 V	- 40°C to 125°C		120	188	μs

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated



### 7.5 Electrical Characteristics (continued)

Unless otherwise noted, the characteristics in the following table apply across the recommended operating input voltage range with a load of  $C_1 = 0.1 \, \mu\text{F}$ ,  $R_1 = 100 \, \Omega$ . Typical Values are at 5 V and  $T_A = 25 \, ^{\circ}\text{C}$ .

-	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
		R <sub>ILIM</sub> = 624 Ω	- 40°C to 125°C	1.2	1.6	1.9	Α
I <sub>HCD</sub>	High current detection threshold (TPS22950L)	R <sub>ILIM</sub> = 1.25 k Ω	- 40°C to 125°C	0.6	0.85	1.1	Α
	(11 5225552)	R <sub>ILIM</sub> = 2.5 k Ω	- 40°C to 125°C	0.3	0.47	1.9	Α
Reverse C	urrent Blocking (TPS22950)	1					
\/	Activation Threshold	V <sub>OUT</sub> Rising; V <sub>OUT</sub> > V <sub>IN</sub>	- 40°C to 125°C		44		mV
$V_{RCB}$	Release Threshold	V <sub>OUT</sub> Falling; V <sub>OUT</sub> > V <sub>IN</sub>	- 40°C to 125°C		16		mV
t <sub>RCB</sub>	Response Time	V <sub>OUT</sub> = V <sub>IN</sub> + 1 V	- 40°C to 125°C		3		μs
I <sub>OUT,RCB</sub>	Reverse Leakage Current into VOUT	$V_{ON} \leqslant V_{IL}$ $V_{IN} = 0 \text{ V, } V_{OUT} = 5 \text{ V}$	- 40°C to 125°C			38	μA
Fault Indic	cation (FLT)						
V <sub>OL, FLT</sub>	Output Low Voltage	I <sub>FLT</sub> = 1 mA	- 40°C to 125°C			0.1	V
t <sub>D,FLT</sub>	Fault Delay Time	$V_{ON} \geqslant V_{IH}$	- 40°C to 125°C		10		μs
I <sub>FLT</sub>	Off State Leakage	$V_{ON} \leqslant V_{IL}$	- 40°C to 125°C			50	nA
Enable Pir	ı (ON)						
R <sub>PD, ON</sub>	Smart Pull Down Resistance	$V_{ON} \leqslant V_{IL}$	- 40°C to 125°C		500	650	kΩ
I <sub>ON</sub>	ON Pin Leakage	$V_{ON} \geqslant V_{IH}$	- 40°C to 125°C			50	nA
		$V_{IN} = 5 V$ $V_{ON} \le V_{IL}$	- 40°C to 125°C		100	160	Ω
$R_{QOD}$	Quick Output Discharge Resistance	$V_{IN}$ = 3.3 V $V_{ON} \leqslant V_{IL}$	- 40°C to 125°C		150	185	Ω
		$V_{IN}$ = 1.8 V $V_{ON} \leqslant V_{IL}$	- 40°C to 125°C		200	355	Ω
Thermal S	hutdown (TSD)						
TSD	Thermal Shutdown	Rising	N/A		170		°C
וטט	THEITHAI SHULUOWH	Falling (Hysteresis)	N/A		150	1.6 1.9 85 1.1 47 0.65 44 16 3 38 0.1 10 50 00 650 50 00 160 50 185 00 355	°C

### 7.6 Switching Characteristics

Unless otherwise noted, the typical characteristics in the following table applies at 25°C with a load of  $C_L$  = 1  $\mu$ F,  $R_L$  = 100  $\Omega$ 

	PARAMETER	TEST CONDITIONS	MIN TYP MA	
		V <sub>IN</sub> = 5 V	800	μs
t <sub>ON</sub>	Turn ON Time	V <sub>IN</sub> = 3.3 V	550	μs
		V <sub>IN</sub> = 1.8 V	400	μs
		V <sub>IN</sub> = 5 V	600	μs
t <sub>R</sub>	Output Rise Time	V <sub>IN</sub> = 3.3 V	320	μs
		V <sub>IN</sub> = 1.8 V	200	μs
		V <sub>IN</sub> = 5 V	260	μs
t <sub>D</sub>	Output Delay Time	V <sub>IN</sub> = 3.3 V	250	μs
		V <sub>IN</sub> = 1.8 V	260	μs
		V <sub>IN</sub> = 5 V	20	μs
t <sub>OFF</sub>	Turn OFF Time	V <sub>IN</sub> = 3.3 V	15	μs
		V <sub>IN</sub> = 1.8 V	17	μs

Product Folder Links: TPS22950

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

7



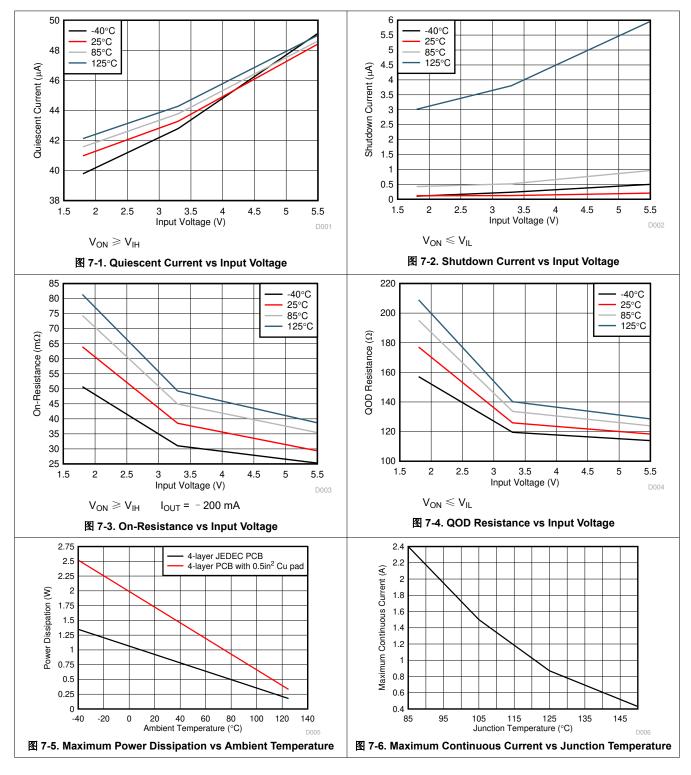
Unless otherwise noted, the typical characteristics in the following table applies at 25°C with a load of  $C_L$  = 1  $\mu$ F,  $R_L$  = 100  $\Omega$ 

	PARAMETER	PARAMETER TEST CONDITIONS			
		V <sub>IN</sub> = 5 V	118		μs
t <sub>FALL</sub>	Output Fall Time	V <sub>IN</sub> = 3.3 V	120		μs
		V <sub>IN</sub> = 1.8 V	130		μs

Product Folder Links: TPS22950



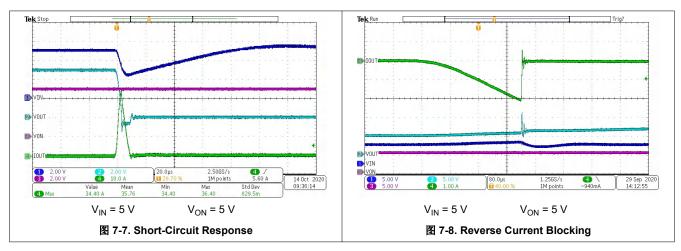
### 7.7 Typical Characteristics



English Data Sheet: SLVSFJ2



# 7.7 Typical Characteristics (continued)



Product Folder Links: TPS22950



### **8 Parameter Measurement Information**

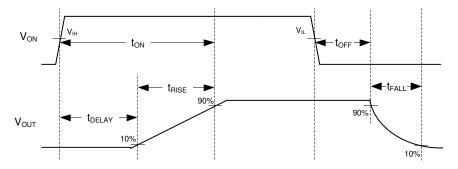


图 8-1. Timing Waveform

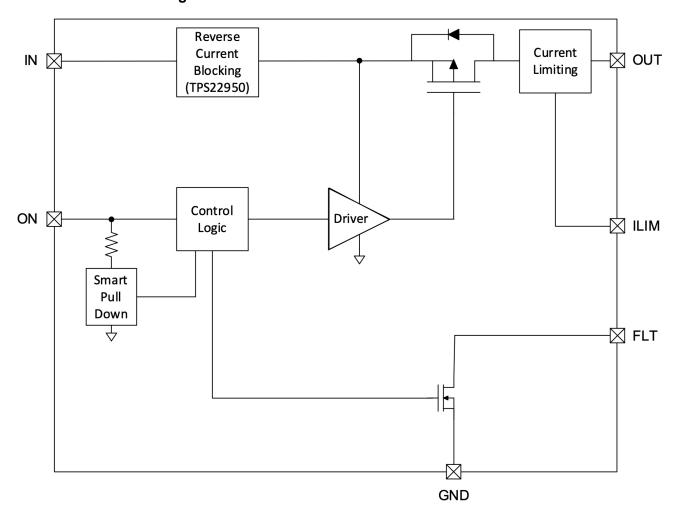
### 9 Detailed Description

### 9.1 Overview

The TPS22950x is a single channel load switch with a 34-m $\Omega$  power MOSFET capable of driving loads up to 3.2 A. While on, the device provides protection against fault cases though its adjustable output current limiting and thermal shutdown. The TPS22950 responds to overcurrent events with auto-retry behavior, while the TPS22950L uses a debounce time and latch off behavior. The TPS22950 also provides reverse current blocking for when VOUT exceeds VIN.

The switch ON state is controlled by a digital input that is capable of interfacing directly with low-voltage control signals, and a smart pulldown is used to keep the ON pin from floating until system sequencing is complete. When the device is turned off, quick output discharge is enabled, pulling the output voltage down to 0 V through a resistive path to GND.

#### 9.2 Functional Block Diagram



### 9.3 Feature Description

#### 9.3.1 Current Limiting (TPS22950, TPS22950C)

The TPS22950 responds to overcurrent conditions by limiting its output current to the  $I_{LIM}$  level shown in the figure below.

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

English Data Sheet: SLVSFJ2



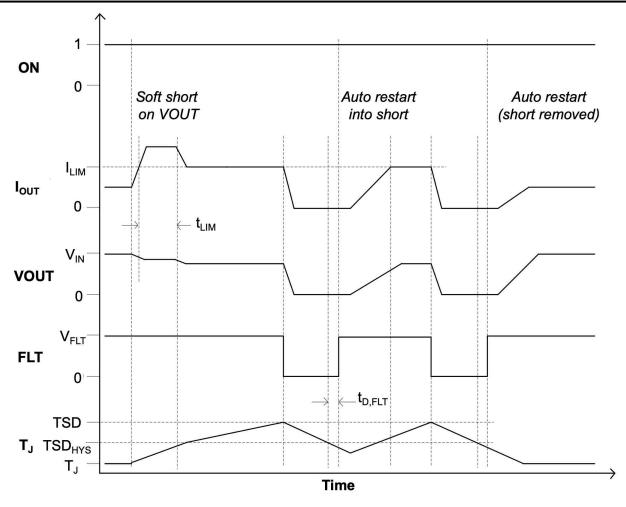


图 9-1. Output Current Limit for Short-Circuit Protection (t<sub>LIM</sub>)

When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Two possible overload conditions can occur.

The first condition is when a short circuit or partial short circuit is present on the output and the ON pin is toggled high, turning the device on. The output voltage is held near zero potential with respect to ground and the TPS22950 ramps the output current to  $I_{LIM}$ . The TPS22950 device limits the current to  $I_{LIM}$  until the overload condition is removed or the internal junction temperature of the device reaches thermal shutdown and the device turns itself off. The device remains off until the junction temperature has lowered to TSD<sub>HYS</sub>, and the device turns itself back on. This action cycles until the overload condition is removed.

The second condition is when a short circuit, partial short circuit, or transient overload occurs after the device has been fully powered on. The device responds to the overcurrent condition within time  $t_{LIM}$  (see figure below), and before this time the current is able to exceed  $I_{LIM}$ . In the case of a fast transient, the current-sense amplifier is over-driven and momentarily disables the internal power FET. The current-sense amplifier recovers and limits the output current to  $I_{LIM}$ . Similar to the previous case, the TPS22950 limits the current to  $I_{LIM}$  until the overload condition is removed or the internal junction temperature of the device reaches thermal shutdown and begins thermally cycling on and off.



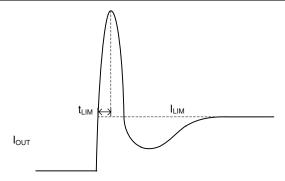


图 9-2. Transient Current Limit Waveform

### 9.3.2 Current Limiting (TPS22950L)

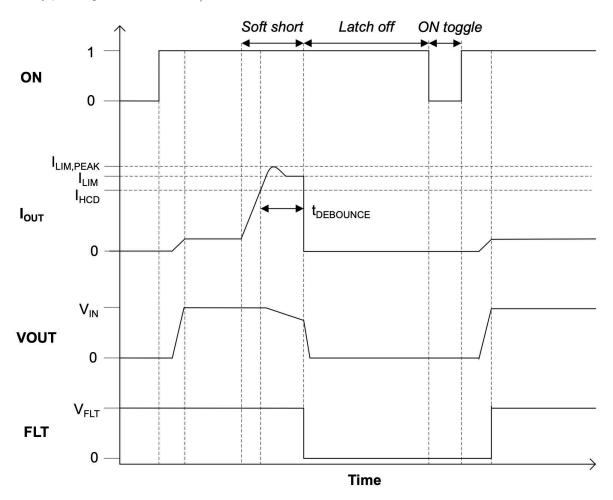


图 9-3. Output Current Limit Behavior

When an overcurrent condition is detected, the device maintains a constant output current and reduces the output voltage accordingly. Two possible overload conditions can occur.

The first condition is when a short circuit or partial short circuit is present on the output and the ON pin is toggled high, turning the device on. The output voltage is held near zero potential with respect to ground and the

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

English Data Sheet: SLVSFJ2

TPS22950L ramps the output current to  $I_{LIM}$ . The TPS22950L device limits the current to  $I_{LIM}$  until the overload condition is removed. If the internal junction temperature of the device reaches thermal shutdown ,the device turns itself off. The device remains off until the junction temperature has lowered to  $TSD_{HYS}$ , and the device turns itself back on. If thermal shutdown is not reached, the device waits for the load current to exceed the high current detection level ( $I_{HCD}$ ) for the  $I_{DEBOUNCE}$  time and latch itself off. The FLT pin is pulled low, and the device is only able to turn on again by toggling the VIN or ON pins.

The second condition is when a short circuit, partial short circuit, or transient overload occurs after the device has been fully powered on. The device responds to the overcurrent condition within time  $t_{LIM}$  (see  $\boxed{8}$  9-4), and before this time the current is able to exceed  $I_{LIM}$ . In the case of a fast transient, the current-sense amplifier is over-driven and momentarily disables the internal power FET. The current-sense amplifier recovers and limits the output current to  $I_{LIM}$ . Similar to the previous case, the TPS22950L limits the current to  $I_{LIM}$  until the overload condition is removed, the debounce time of 120  $\mu$ s is reached, or the internal junction temperature of the device reaches thermal shutdown and begins thermally cycling on and off.

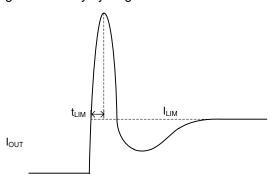


图 9-4. Transient Current Limit Waveform

#### 9.3.3 Adjusting the Current Limit

The current limit is adjusted by connecting an external resistor from the ILIM pin to GND. The current limit resistor can be chosen using the equation:

$$I_{LIM} = 1.18 \times (R_{ILIM})^{-1.072}$$
 (1)

The units for the equation are amps for  $I_{LIM}$  and kilohms for  $R_{ILIM}$ . For the TPS22950L, the device is only limiting current during a short period of time. Therefore, the peak value of the current ( $I_{LIM,PEAK}$ ) may be more applicable for system considerations. The equation for this parameter is below:

$$I_{LIM,PEAK} = 1.31 \times (R_{ILIM})^{-1.042}$$
 (2)

The R<sub>ILIM</sub> resistor is also used to set the high current detection threshold for the TPS22950L, and that equation is shown below.

$$I_{HCD} = (0.988 / R_{ILIM}) + 0.06 \tag{3}$$

The units for the equation are amps for  $I_{HCD}$  and kilohms for  $R_{ILIM}$ .

### 9.3.4 Reverse Current Blocking (TPS22950, TPS22950C)

In a scenario where the device is enabled and  $V_{OUT}$  is greater than  $V_{IN}$ , there is potential for reverse current to flow through the pass FET or the body diode. When the reverse current threshold is exceeded (about 900 mA), there is a delay time ( $t_{RCB}$ ) before the switch turns off to stop the current flow. The switch remains off and block reverse current as long as the reverse voltage condition exists. After  $V_{OUT}$  has dropped below the release voltage threshold ( $V_{RCB}$ ) the device turns back on. When the ON pin is pulled low, the device constantly blocks reverse current.

#### 9.4 Device Functional Modes

The tables below summarize the Device Functional Modes.

Copyright © 2023 Texas Instruments Incorporated

Submit Document Feedback

15



### 表 9-1. Output Connection Table

ON	Fault Condition	VOUT State	FLT State
L	N/A	Hi-Z	Hi-Z
Н	None	VIN (via R <sub>ON</sub> )	Hi-Z
Н	Output short	Current Limited	Hi-Z
Н	Thermal shutdown	Hi-Z	L
Н	Reverse current	Hi-Z	L

# 表 9-2. Smart-ON Functional Modes ( $R_{PD,ON}$ )

ON	ON Pin
$\leq$ $V_{IL}$	Pulldown active
≥ V <sub>IH</sub>	No pulldown

Product Folder Links: TPS22950

Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

### 10 Application and Implementation

#### 备注

以下应用部分中的信息不属于 TI 器件规格的范围, TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

### 10.1 Application Information

This section highlights some of the design considerations when implementing this device in various applications.

### 10.2 Typical Application

This typical application demonstrates how the TPS22950x device can be used to set an adjustable current limit.

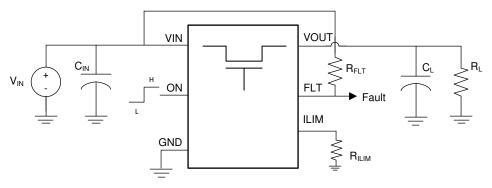


图 10-1. Typical Application

#### 10.2.1 Design Requirements

For this example, the values below are used as the design parameters.

#### 表 10-1. Design Parameters

PARAMETER	VALUE
Input Voltage (V <sub>IN</sub> )	5 V
Load Current (mA)	100 mA
Typical Current Limit (mA)	500 mA

#### 10.2.2 Detailed Design Procedure

In this example the nominal load current is 100 mA, so the current limit can be set to 500 mA without disrupting normal operation. Use 方程式 4 to calculate the resistor needed on the ILIM pin.

$$I_{LIM} = 1.18 \times (R_{ILIM})^{-1.072}$$
 (4)

where

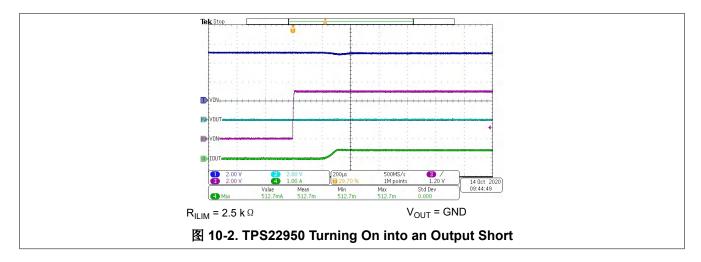
- I<sub>LIM</sub> = Typical current limit setting
- R<sub>ILIM</sub> = Resistor on the ILIM pin

Based on 方程式 4, a 2.21-k Ω resistor must be used on the ILIM pin to set a typical current limit of 500 mA.

English Data Sheet: SLVSFJ2

### 10.2.3 Application Curves

The below scope shot shows the device turning on into a fault condition and limiting the current to the specified amount of 500 mA.



### 10.3 Power Supply Recommendations

The device is designed to operate with a VIN range of 1.8 V to 5.5 V. The VIN power supply must be well regulated and placed as close to the device terminal as possible. The power supply must be able to withstand all transient load current steps. In most situations, using an input capacitance (CIN) of 1  $\mu$ F is sufficient to prevent the supply voltage from dipping when the switch is turned on. In cases where the power supply is slow to respond to a large transient current or large load current step, additional bulk capacitance may be required on the input.

#### 10.4 Layout

#### 10.4.1 Layout Guidelines

For best performance, all traces must be as short as possible. To be most effective, the input and output capacitors must be placed close to the device to minimize the effects that parasitic trace inductances may have on normal operation. Using wide traces for VIN, VOUT, and GND helps minimize the parasitic electrical effects.

Product Folder Links: TPS22950



### 10.4.2 Layout Example

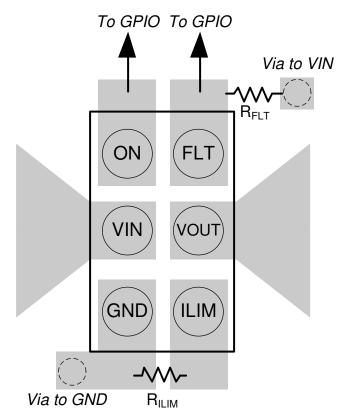


图 10-3. TPS22950x WCSP Layout Example

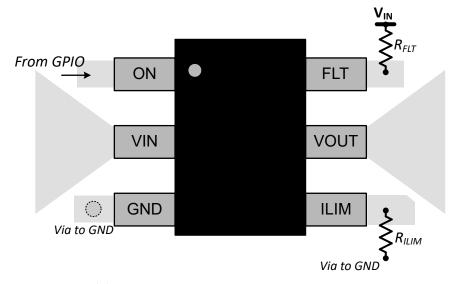


图 10-4. TPS22950C SOT6 Layout Example



### 11 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

#### 11.1 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册,即可每周接收产品信息更改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

#### 11.2 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料,可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI 的《使用条款》。

Product Folder Links: TPS22950

#### 11.3 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

#### 11.4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序,可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

#### 11.5 术语表

TI术语表本术语表列出并解释了术语、首字母缩略词和定义。

Copyright © 2023 Texas Instruments Incorporated



### 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



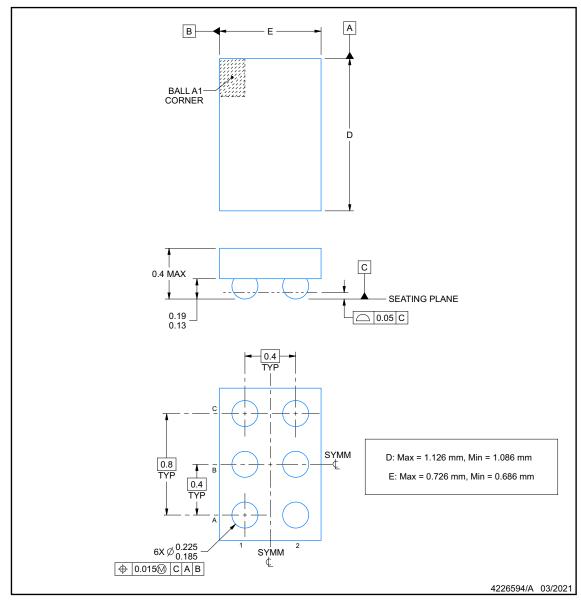
# YBH0006-C02



### **PACKAGE OUTLINE**

### DSBGA - 0.4 mm max height

DIE SIZE BALL GRID ARRAY



### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.



Product Folder Links: TPS22950

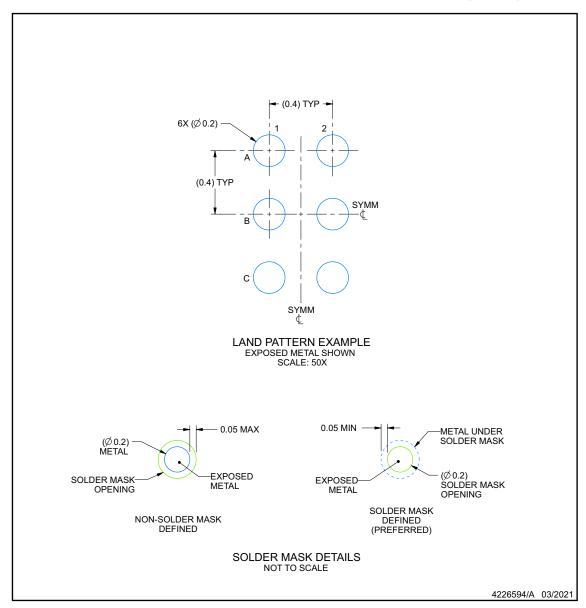
Copyright © 2023 Texas Instruments Incorporated

### **EXAMPLE BOARD LAYOUT**

### YBH0006-C02

### DSBGA - 0.4 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).



Product Folder Links: TPS22950

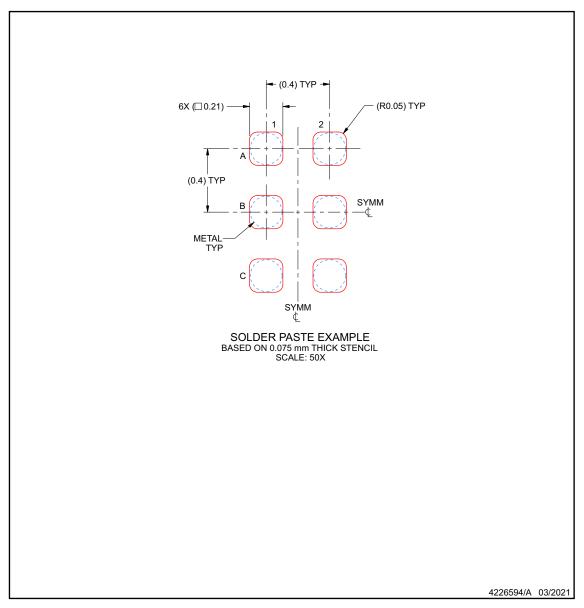


### **EXAMPLE STENCIL DESIGN**

# YBH0006-C02

DSBGA - 0.4 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



Submit Document Feedback

Copyright © 2023 Texas Instruments Incorporated

www.ti.com 14-Apr-2023

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS22950CDDCR	ACTIVE	SOT-23-THIN	DDC	6	3000	RoHS & Green	Call TI   SN	Level-1-260C-UNLIM	-40 to 125	950C	Samples
TPS22950LYBHR	ACTIVE	DSBGA	YBH	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125	4	Samples
TPS22950YBHR	ACTIVE	DSBGA	YBH	6	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 125		Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

## **PACKAGE OPTION ADDENDUM**

www.ti.com 14-Apr-2023

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF TPS22950:

Automotive : TPS22950-Q1

NOTE: Qualified Version Definitions:

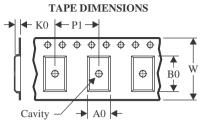
• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 30-Dec-2023

### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22950CDDCR	SOT-23- THIN	DDC	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS22950LYBHR	DSBGA	YBH	6	3000	180.0	8.4	0.8	1.21	0.43	2.0	8.0	Q1
TPS22950YBHR	DSBGA	YBH	6	3000	180.0	8.4	0.8	1.21	0.43	2.0	8.0	Q1

www.ti.com 30-Dec-2023



### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22950CDDCR	SOT-23-THIN	DDC	6	3000	210.0	185.0	35.0
TPS22950LYBHR	DSBGA	YBH	6	3000	182.0	182.0	20.0
TPS22950YBHR	DSBGA	YBH	6	3000	182.0	182.0	20.0

### 重要声明和免责声明

TI"按原样"提供技术和可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证没有瑕疵且不做出任何明示或暗示的担保,包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任:(1) 针对您的应用选择合适的 TI 产品,(2) 设计、验证并测试您的应用,(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更,恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务,TI 对此概不负责。

TI 提供的产品受 TI 的销售条款或 ti.com 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023,德州仪器 (TI) 公司